# Integrated Relay, Inductive Load Driver

This device is used to switch inductive loads such as relays, solenoids incandescent lamps, and small DC motors without the need of a free—wheeling diode. The device integrates all necessary items such as the MOSFET switch, ESD protection, and Zener clamps. It accepts logic level inputs thus allowing it to be driven by a large variety of devices including logic gates, inverters, and microcontrollers.

#### **Features**

- Provides a Robust Driver Interface Between D.C. Relay Coil and Sensitive Logic Circuits
- Optimized to Switch Relays of 12 V Rail
- Capable of Driving Relay Coils Rated up to 6.0 W at 12 V
- Internal Zener Eliminates the Need of Free-Wheeling Diode
- Internal Zener Clamp Routes Induced Current to Ground for Quieter Systems Operation
- Low V<sub>DS(ON)</sub> Reduces System Current Drain

## **Typical Applications**

- Telecom: Line Cards, Modems, Answering Machines, FAX
- Computers and Office: Photocopiers, Printers, Desktop Computers
- Consumer: TVs and VCRs, Stereo Receivers, CD Players, Cassette Recorders
- Industrial:Small Appliances, Security Systems, Automated Test Equipment, Garage Door Openers



# ON Semiconductor®

http://onsemi.com

# Relay, Inductive Load Driver Silicon SMALLBLOCK™ 0.5 Ampere, 16 V Clamp



### SOT-23 CASE 318 STYLE 21

#### MARKING DIAGRAMS



JW5 = Specific Device Code D = Date Code

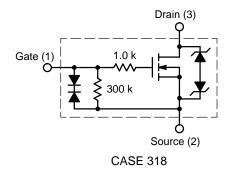


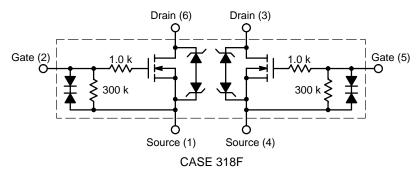
SC-74<sup>2</sup>
CASE 318F
STYLE 7



JW5 = Specific Device Code D = Date Code

## INTERNAL CIRCUIT DIAGRAMS





# ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NUD3112LT1	SOT-23	3000/Tape & Reel
NUD3112DMT1	SC-74	3000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# **MAXIMUM RATINGS** ( $T_J = 25^{\circ}C$ unless otherwise specified)

Symbol	Rating		Value	Unit
V <sub>DSS</sub>	Drain to Source Voltage – Continuous		14	V <sub>dc</sub>
$V_{GS}$	Gate to Source Voltage – Continuous		6	V <sub>dc</sub>
I <sub>D</sub>	Drain Current – Continuous		500	mA
Ez	Single Pulse Drain-to-Source Avalanche Energy (T <sub>Jinitial</sub> = 25°C)		50	mJ
TJ	Junction Temperature		150	°C
T <sub>A</sub>	Operating Ambient Temperature		-40 to 85	°C
T <sub>stg</sub>	Storage Temperature Range		-65 to +150	°C
P <sub>D</sub>	Total Power Dissipation (Note 1) Derating Above 25°C	SOT-23	225 1.8	mW mW/°C
P <sub>D</sub>	Total Power Dissipation (Note 1) Derating Above 25°C	SC-74	380 1.5	mW mW/°C
$R_{ heta JA}$	Thermal Resistance Junction-to-Ambient (Note 1)	SOT-23 SC-74	556 329	°C/W
ESD	Human Body Model (HBM) According to EIA/JESD22/A114		2000	V

<sup>1.</sup> Mounted onto minimum pad board.

# TYPICAL ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Characteristic	Min	Тур	Max	Unit	
OFF CHAR	OFF CHARACTERISTICS					
V <sub>BRDSS</sub>	Drain to Source Sustaining Voltage (Internally Clamped) (ID = 10 mA)	14	16	17	V	
B <sub>VGSO</sub>	I <sub>g</sub> = 1.0 mA	-	-	8	V	
I <sub>DSS</sub>	Drain to Source Leakage Current $(V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}, T_A = 25^{\circ}\text{C})$ $(V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}, T_A = 85^{\circ}\text{C})$	_ _	- -	20 40	μΑ	
I <sub>GSS</sub>	Gate Body Leakage Current $(V_{GS} = 3.0 \text{ V}, V_{DS} = 0 \text{ V})$ $(V_{GS} = 5.0 \text{ V}, V_{DS} = 0 \text{ V})$	- -	- -	35 65	μΑ	
ON CHARA	CTERISTICS	•		•		
V <sub>GS(th)</sub>	Gate Threshold Voltage $ (V_{GS} = V_{DS}, I_D = 1.0 \text{ mA}) $ $ (V_{GS} = V_{DS}, I_D = 1.0 \text{ mA}, T_A = 85^{\circ}\text{C}) $	0.8 0.8	1.2 -	1.4 1.4	V	
R <sub>DS(on)</sub>	Drain to Source On–Resistance $ \begin{array}{l} (I_D = 250 \text{ mA}, \text{ V}_{GS} = 3.0 \text{ V}) \\ (I_D = 500 \text{ mA}, \text{ V}_{GS} = 3.0 \text{ V}) \\ (I_D = 500 \text{ mA}, \text{ V}_{GS} = 5.0 \text{ V}) \\ (I_D = 500 \text{ mA}, \text{ V}_{GS} = 5.0 \text{ V}, \text{ T}_{A} = 85 ^{\circ}\text{C}) \\ (I_D = 500 \text{ mA}, \text{ V}_{GS} = 5.0 \text{ V}, \text{ T}_{A} = 85 ^{\circ}\text{C}) \end{array} $	- - - -	- - - -	1.2 1.3 0.9 1.3 0.9	Ω	
I <sub>DS(on)</sub>	Output Continuous Current $ (V_{DS}=0.25 \text{ V}, V_{GS}=3.0 \text{ V}) \\ (V_{DS}=0.25 \text{ V}, V_{GS}=3.0 \text{ V}, T_{A}=85^{\circ}\text{C}) $	300 200	400 -	<u>-</u> -	mA	
9FS	Forward Transconductance (V <sub>OUT</sub> = 12.0 V, I <sub>OUT</sub> = 0.25 A)	350	490	-	mmhos	

# TYPICAL ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

	· //	,			
Symbol	Characteristic	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS					
C <sub>iss</sub>	Input Capacitance (V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 0 V, f = 10 kHz)	-	23	-	pF
C <sub>oss</sub>	Output Capacitance $(V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}, f = 10 \text{ kHz})$	-	30	-	pF
C <sub>rss</sub>	Transfer Capacitance $(V_{DS} = 12.0 \text{ V}, V_{GS} = 0 \text{ V}, f = 10 \text{ kHz})$	-	7	_	pF

# **SWITCHING CHARACTERISTICS**

Symbol	Characteristic	Min	Тур	Max	Units
	Propagation Delay Times:		0.4		nS
t <sub>PHL</sub>	High to Low Propagation Delay; Figure 1 (V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 5.0 V)	_	21	_	
t <sub>PLH</sub>	Low to High Propagation Delay; Figure 1 ( $V_{DS} = 12 \text{ V}, V_{GS} = 5.0 \text{ V}$ )	_	91	_	
	Transition Times:				nS
t <sub>f</sub>	Fall Time; Figure 1 (V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 5.0 V)	_	36	_	
t <sub>r</sub>	Rise Time; Figure 1 ( $V_{DS} = 12 \text{ V}, V_{GS} = 5.0 \text{ V}$ )	_	61	_	

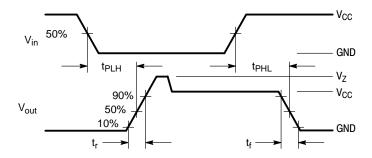
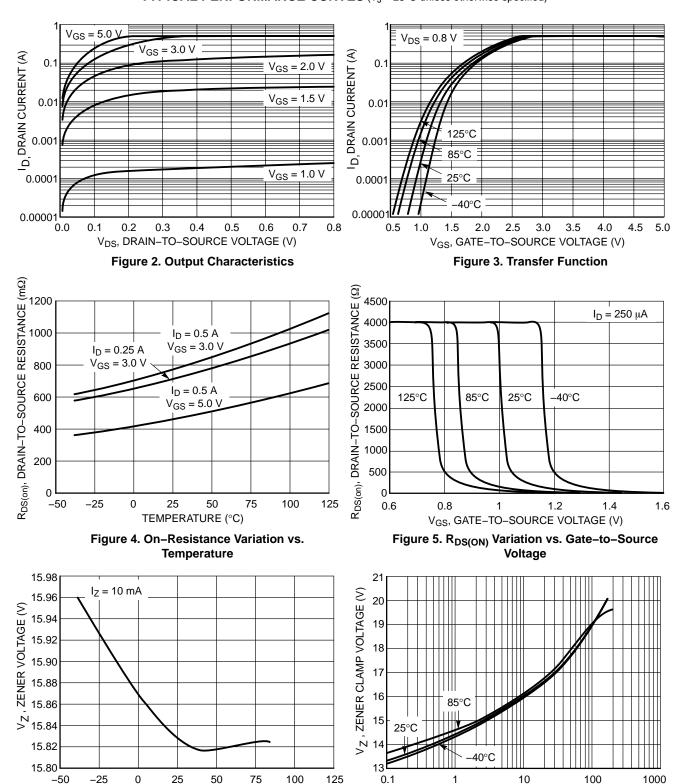


Figure 1. Switching Waveforms

# TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = 25°C unless otherwise specified)



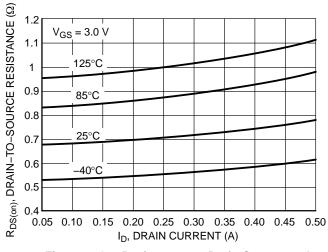
TEMPERATURE (°C)

Figure 6. Zener Voltage vs. Temperature

Figure 7. Zener Clamp Voltage vs. Zener Current

IZ, ZENER CURRENT (mA)

# TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = 25°C unless otherwise specified)



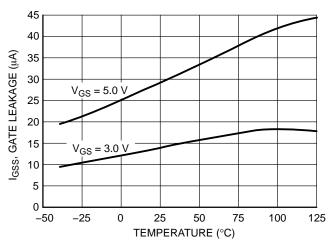


Figure 8. On–Resistance vs. Drain Current and Temperature

Figure 9. Gate Leakage vs. Temperature

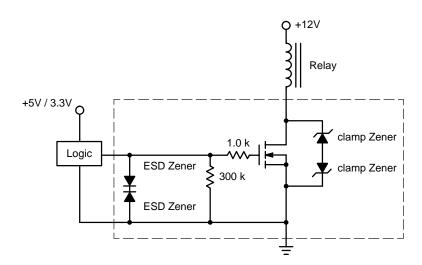


Figure 10. Typical Application Circuit

# **PACKAGE DIMENSIONS**

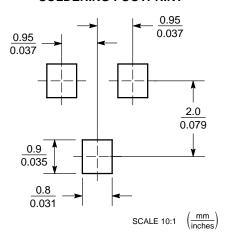
SOT-23 (TO-236) CASE 318-08 **ISSUE AH** 

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  4. 318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.

	INC	CHES	MILLIM	IETERS
DIM	MIN	MAX	MIN MAX	
A	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
Н	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
Ĺ	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 21:
PIN 1. GATE
2. SOURCE
3. DRAIN

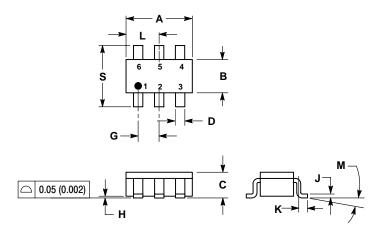
#### **SOLDERING FOOTPRINT\***



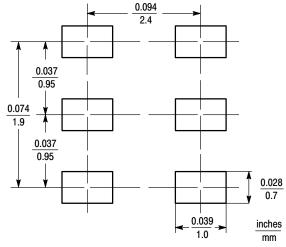
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# PACKAGE DIMENSIONS

SC-74 CASE 318F-05 ISSUE K



# SOLDERING FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

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  2. CONTROLLING DIMENSION: INCH.

  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

  4. 318F-01, -02, -03 OBSOLETE. NEW STANDARD 318F-04.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN MAX	
Α	0.1142	0.1220	2.90	3.10
В	0.0512	0.0669	1.30	1.70
С	0.0354	0.0433	0.90	1.10
D	0.0098	0.0197	0.25	0.50
G	0.0335	0.0413	0.85	1.05
Н	0.0005	0.0040	0.013	0.100
J	0.0040	0.0102	0.10	0.26
K	0.0079	0.0236	0.20	0.60
L	0.0493	0.0649	1.25	1.65
М	0 °	10°	0 °	10°
S	0.0985	0 1181	2 50	3 00

- STYLE 7: PIN 1. SOURCE 1 2. GATE 1 3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1

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